

EUV/SXR Optics and Metrology Development at RITE

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Rigaku Innovative Technologies Europe Ltd. (RITE), Prague, Czech Republic

Electromagnetic radiation spectrum



D. T. Attwood Soft X-rays and Extreme Ultraviolet Radiation: Principles and Applications (Cambridge University Press, Cambridge, 1999)



Berkeley, CA, June 12–15, 2017



Pinching Plasmas Capillary Discharge Plasma



Design and construction of new experimental capillary discharge apparatus (A. Jancarek, M. Nevrkla) CTU Prague, Faculty of Nuclear Sciences

2017 International Workshop on EUV Lithography, CXRO, LBNL,

Berkeley, CA, June 12–15, 2017

Laser Produced Plasma – gas puff target





• electromagnetic valve system

• X-ray backlighting images



H. Fiedorowicz *et al. Appl.Phys. B 70 (2000) 305; Patent No.: US 6,469,310 B1* WAT , Warszaw 2017 International Workshop on EUV Lithography, CXRO, LBNL, Berkeley, CA, June 12–15, 2017



LPP - Gas puff target EUV laser-plasma short wavelength source



Scheme of the gas-puff target source



Photograph of the setup

Advantages:

- ✓ no debris from gaseous targets
- ✓ compact construction, high repeatability
- ✓ high conversion efficiency, very robust thousands of shots/day

Pumping laser	Nd:YAG laser (EKSPLA), 4 ns/500mJ	
	pulses, repetition rate 10Hz	
Nozzle	Inner: circular 0.4mm in diameter	
	Outer: ring 0.7mm/1.5mm diameters	
Gasses	Working gasses: Ar, Kr, Xe, O ₂ , N ₂ ,	
	outer gas : <mark>He</mark>	

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LPP - Gas puff target EUV laser-plasma short wavelength source spectra

Argon emission in the "water window"



Nitrogen emission in the "water window"



EUV/XUV/XR sources

Synchrotron and FEL radiation

Reflection of X-rays

Complex refractive index $\mathbf{n} = \mathbf{1} - \delta - i\beta$

Refraction and Reflection of X-rays



Total external reflection

Reflection of X-rays – photon energy and grazing angle



Reflection of X-rays – microroughness



Tapping AFM images of the surface of the double - sided flats developed for Schmidt lobster-eye telescopes. The resulting microroughness RMS is 0.3 nm.

Grazing Incidence (GI) replicated X-Ray Optics 48 years of research and development in Prague

Replication Technology for X-ray Optics Manufacturing



Mandrels used for manufacturing of X-ray mirrors (Glass ceramics Sital, Acad of Sci, Prague, 1969)



Replicated X-ray mirrors (hyperbolas, Ni surfaces, Acad of Sci, Prague)

History – milestones and examples of projects

(Academy of Science, Czech Technical University, Reflex, Rigaku)

- 1969 First considerations started
- 1970 First X-ray mirror produced (Wolter 1, 50 mm)
- 1971 Wolter 1, 80 mm
- 1976 Wolter 1, 115 mm
- 1979 First mirrors flown in space (two Wolter 50 mm, Vertikal 9 rocket)
- 1980 Vertikal 11 rocket (two Wolter 50 mm)
- 1981 First large Wolter mirror (240 mm)
- 1981 Salyut 7 orbital station (Wolter 240 mm nested)
- 1985 Applications for plasma physics, EH 17 mm, PP 20 mm
- 1987 First high quality X-ray foils for foil mirror X-ray telescope (SODART)
- 1988 Fobos 1 Mars probe, TEREK X-Ray Telescope
- 1989 KORONAS I X-ray mirror, Wolter 80 mm
- 1990 First Micromirror (aperture less than 1 mm, Bede Ltd.)
- 1993 Collaboration with SAO, USA, WF X-ray optics started
- 1996 First Lobster Eye test module produced, Schmidt geometry
- 1997 Double-sided X-ray reflecting flats (SAO MA USA, CTU Prague)
- 1997 Lobster Eye Angel geometry project started
- 1999 First Lobster Eye test module produced, Angel geometry
- 2001 Thin segmented X-ray mirrors
- 2005 Replicated Image Slicers for LEO, EU FP6 projects, Cambridge
- 2006 MFO Kirkpatrick-Baez optic, University of Boulder, CO, NASA, USA
- 2007 Innovative technologies for X-ray telescopes, PECS, ESA XEUS projects
- 2008 2017 EUV/BEUV/WW/SXR/XR Grazing Incidence mirrors ...

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Examples of Imaging GI X-ray optics



Replication technology



MANDREL with Au surface layer

Ellipsoidal mirror for spectral region 10 – 15 nm

Replication technology

- Replication technology developments in the Czechoslovak Acad. of Sci., National Research Institute for Materials (1969)
 - 2-3 mirrors from one master
- Improvement of replication technology:
 - less damage of mandrel
 - reduced weight
- Laboratory and space applications

- - a master,
 - b master with electroformed nickel layer
 - d cutting/finishing of the edges
 - e removing the Ni mirror shell
- Wolter objectives 17 mm and 20 mm dia
- EH Wolter used (1985) for taking photographs of laser plasma in Institute of Plasma Physics and Laser Microfusion in Warsaw



Example: Elliptical mirror

- Mirror surface has shape of • rotational ellipsoid Source is placed in left focus
- Detector or sample is placed in right focus
- mirror Radiation strikes surface at grazing angles 0,5° ÷ 20°
- Mirror is focusing radiation ٠ from left focus on right focus



GI Mirrors – Spectral Range

- Metallic surface (Au, Ni, Mo, Ru...)
- $R \ge 50\%$
- Grazing angles: 0.5° 20°
- Surface roughness: $R_a \approx 0.2 2 \text{ nm}$
- Dimensions: D = 5 300 mm
 L = 10 250 mm
- Optical shapes: elliptical, parabolic, aspherical shapes upon request
- Spectral range: EUV (60 200 eV) Soft X-ray (200 – 2000 eV) X-ray (2 - 20 keV)









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Ellipsoidal mirror for 8 keV microfocus source



Ellipsoidal optic for 8 keV microfocus source



A series of X-ray beam images behind the output of ellipsoidal mirror with beam stop on the axis.

Converging reflected beam and diverging direct beam are clearly distinguishable.



Ellipsoidal X-ray Mirror as a Spectral Filter



XGI Mirrors Manufactured by Rigaku Innovative Technologies Europe (RITE)

- RITE is the Czech company owned by the Rigaku Corporation (Tokyo, Japan)
- Established in 2008 as European center for the design, development and manufacturing of X-ray optics, X-ray detectors and X-ray sources
- Colaboration with Czech academic institutions and high-tech companies
- Ellipsoidal and parabolic optics for EUV/BEUV/WW/SXR/XR (laser plasma research, EUVL, WW and X-ray microscopy, space, ...)
- Slope error < 10 arcsec (5"), microroughness < 2 nm (0.5 nm)





Replicated GI Mirrors Applications

Ellipsoidal GI mirror for WW (2.3 – 4.4 nm)





Ellipsoidal GI mirror For EUVL (10-15 nm)



Laser-plasma produced EUV source: laser 0.8 J / 4 ns





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Laser plasma EUV source for processing polymers

Laser plasma EUV source dedicated for processing polymers has been designed at IOE and was built in co-operation with EKSPLA, RIGAKU and PREVAC high-tech companies





NANOIMAGING USING SOFT X-RAYS

Desk-top soft X-ray microscope with a laser plasma source





table



EUV IMAGING IN A NANOSCALE

Desk-top soft X-ray microscope with a laser plasma source



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Collector

Focusing of soft X-ray radiation



- 200 nm Ti filter
 → T = 72%
- (before: 1200 nm, T=14% = 1/5 · 72%)
 - phosphor coated CCD → exposure level ~ 80% in focal plane

Dr. Klaus Mann, LLG Gottingen





EUV microscope with capillary discharge plasma source (Nitrogen, $\lambda = 2.88$ nm), ellipsoidal grazing incidence condenser and Fresnel Zone objective (Czech Technical University in Prague)





EUV microscope with capillary discharge plasma source (Nitrogen, λ = 2.88 nm), ellipsoidal grazing incidence condenser and Fresnel Zone objective (Czech Technical University in Prague)



Replicated GI Mirrors Spectral and Focusing Analysis

Focusing system prepared for a soft X-ray plasma source based on Xe gas target, driven by a 10 J/ 1ns/ 10 Hz Nd:YAG laser system



Set of 2 coaxial paraboloidal mirrors optimized for the wavelength 1.5 nm

Plasma





Measurement of GI SXR mirror spectral reflectivity



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Comparison of Au and Ru coated EUV collector reflectivity





Spectra of Xe/He plasma radiation:

- a) Xe plasma emission
- b) Radiation reflected from the Au coated collector surface
- c) Radiation reflected from the Ru coated collector surface



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Detection systems based on paraboloidal moirrors



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Ellipsoidal GI EUV mirror for 13.5 nm



GI EUV Mirrors



Ellipsoidal GI EUV mirror for 13.5 nm



EBL2: EUV exposure and surface analysis system



Multi-foil optics



Wide FOV

- Glass or silicon substrates
- Planar or ellipsoidal mirrors
- Foils 3×3 mm to 300×300 mm
- Thickness from 30 μ m 1 mm
- Wavelength: EUV soft X-ray
- Surface: Au, Ni, Mo, Pt, W, ...



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SECONDARY MIRROR (PARABOLIC 2D)

PRIMARY MIRROR (PARABOLIC 2D)

OPTICS APERTURE



Riaaku

Lobster Eye

- 5 10 keV
- Focal length: 1000 1200 mm
- Imaging: 1:1
- Spot size: 0.5 mm
- FOV: 2°

MFO KB system

- 80 120 eV
- FOV: 20°
- Spot size: 0.5 1.0 mm

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OMMON FOCUS OF BOTH MIRRORS

Lobster Eye



X-ray LE - experiment vs theory

- Point-to-point focusing system
- Source: 20 μm size, 8 keV photons
- Source-detector distance: 1.2 m, 8 keV photons
- Detector: 512x512 pixels, 24x24 μm pixel size
- Intensity Gain: G=570 (experiment) vs. G=584 (comp. simulation)



Focusing of XUV radiation and XUV modification of materials (experiments at CTU, PALS and WAT)



Schematic view of one half of the multi–foil (MFO) XUV bifacial Kirkpatrick-Baez condenser – experiments at WAT, Warsaw.







MF K-B system for EUV lithography

Multilayer optics

(Rigaku Innovative Technologies, Auburn Hills, MA)

- > 20 years of experience (Osmic)
- Design: uniform or graded (lateral, radial, bilateral 2D), depth graded, flat, curved, glancing (< 1°) to normal incidence
- Wavelength range: 40 eV 40 keV
- Number of period: Nmax = 1000
- Size: from 3 1500 mm
- ML period: dmin = 10 Å
- Spectral resolution: $\Delta\lambda/\lambda = 0.3\%$ (high selective) - 20% (depth graded)
- Materials: W/Si, W/C, Ni/Ti, Ni/B₄C, Ni/C, Cr/C, Cr/Sc, Mo/Si, Mo/B₄C, V/C, Ru/B₄C, Al₂O₃/B₄C, SiC/Si, Si/C, SiC/C, Fe/Si, ...









Multilayer optics

(Rigaku Innovative Technologies, Auburn Hills, MA)



Detectors

- High resolution X-ray detectors (small FOV)
- Medium resolution X-ray detectors (bigger FOV)
- X-ray diode detectors
- pA meters

QUANTUM EFFICIENCY MEASUREMENTS (photon number)

PARAMETER	Ar data	N ₂ data
SXR flux (photons/pulse) @ 1.1 m from source	(4.64±0.71)E+8 QE=106.83	(3.01±0.34)E+06 QE=119.5
SXR flux (photons/pulse) @ Ce:YAG plane (N _{inc})	(1.48±0.23)E+11 QE=106.83	(9.60±1.08)E+8 QE=119.5
Scintillated light flux (N _{sc}) (photons/pulse), QE=0.6	(1.03±0.15)E+10	(1.86±0.2)E+08
Nd:YAG scattered photon flux, QE=0.22	(1.29±0.04)E+9	(1.29±0.04)E+9
Photon efficiency =N _{sc} / N _{inc}	6.9%	19.4%

THANK YOU FOR ATTENTION

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